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(5-2008)

# High Speed Infrared Emitting Diodes, 940 nm, GaAlAs, DH



#### **DESCRIPTION**

VSMB2000X01 series are infrared, 940 nm emitting diodes in GaAlAs (DH) technology with high radiant power and high speed, molded in clear, untinted plastic packages (with lens) for surface mounting (SMD).

#### **APPLICATIONS**

- IrDA compatible data transmission
- · Miniature light barrier
- Photointerrupters
- · Optical switch
- · Control and drive circuits
- · Shaft encoders

#### **FEATURES**

Package type: surface-mount

Package form: GW, RGW

• Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.8

AEC-Q101 qualified

Peak wavelength: λ<sub>p</sub> = 940 nm

· High reliability

· High radiant power

· High radiant intensity

• Angle of half intensity:  $\phi = \pm 12^{\circ}$ 

· Low forward voltage

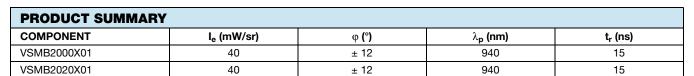
· Suitable for high pulse current operation

· Terminal configurations: gullwing or reserve gullwing

Package matches with detector VEMD2000X01 series

• Floor life: 4 weeks, MSL 2a, according to J-STD-020

 Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>



#### Note

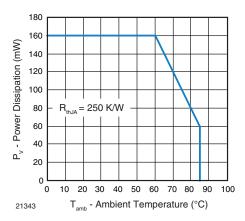
Test conditions see table "Basic Characteristics"

ORDERING INFORMATION					
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM		
VSMB2000X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing		
VSMB2020X01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing		

#### Note

MOQ: minimum order quantity

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Reverse voltage		$V_{R}$	5	V	
Forward current		I <sub>F</sub>	100	mA	
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I <sub>FM</sub>	200	mA	
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1	А	
Power dissipation		P <sub>V</sub>	160	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T <sub>amb</sub>	-40 to +85	°C	
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C	
Soldering temperature	t ≤ 5 s	T <sub>sd</sub>	260	°C	
Thermal resistance junction to ambient	J-STD-051, leads 7 mm, soldered on PCB	R <sub>thJA</sub>	250	K/W	





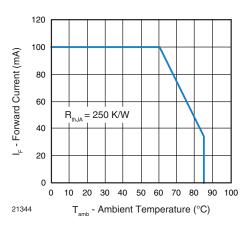


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERISTICS (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V <sub>F</sub>	1.15	1.35	1.6	V
	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	$V_{F}$	-	2.2	-	V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 1 mA	TK <sub>VF</sub>	-	-1.8	-	mV/K
	I <sub>F</sub> = 100 mA	TK <sub>VF</sub>	ı	-1.1	-	mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>	-	-	10	μA
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$	CJ	-	70	-	pF
Park at the art	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l <sub>e</sub>	20	40	60	mW/sr
Radiant intensity	$I_F = 1 \text{ A}, t_p = 100 \mu \text{s}$	l <sub>e</sub>	-	330	-	mW/sr
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	φ <sub>e</sub>	-	40	-	mW
Temperature coefficient of radiant power	I <sub>F</sub> = 1 mA	TKφ <sub>e</sub>	-	-1.1	-	%/K
	I <sub>F</sub> = 100 mA	TKφ <sub>e</sub>	-	-0.51	-	%/K
Angle of half intensity		φ	-	± 12	-	0
Peak wavelength	I <sub>F</sub> = 30 mA	$\lambda_{p}$	920	940	960	nm
Spectral bandwidth	I <sub>F</sub> = 30 mA	Δλ	-	25	-	nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 30 mA	TKλ <sub>p</sub>	-	0.25	-	nm/K
Rise time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>r</sub>	-	15	-	ns
Fall time	I <sub>F</sub> = 100 mA, 20 % to 80 %	t <sub>f</sub>	-	15	-	ns
Cut-off frequency	$I_{DC} = 70 \text{ mA}, I_{AC} = 30 \text{ mA}_{pp}$	f <sub>c</sub>	-	23	-	MHz
Virtual source diameter		d	-	1.5	-	mm

### BASIC CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

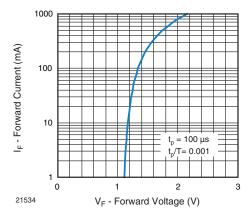


Fig. 3 - Forward Current vs. Forward Voltage

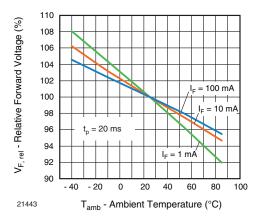


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

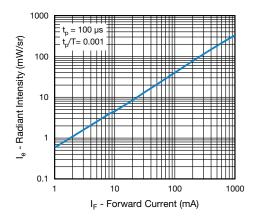


Fig. 5 - Radiant Intensity vs. Forward Current

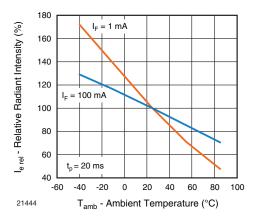


Fig. 6 - Relative Radiant Intensity vs. Ambient Temperature

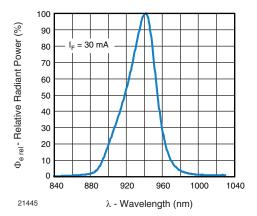


Fig. 7 - Relative Radiant Power vs. Wavelength

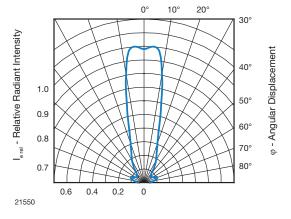


Fig. 8 - Relative Radiant Intensity vs. Angular Displacement



#### **SOLDER PROFILE**

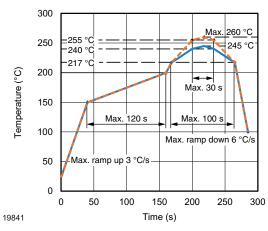


Fig. 9 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020

#### **DRYPACK**

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

#### **FLOOR LIFE**

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

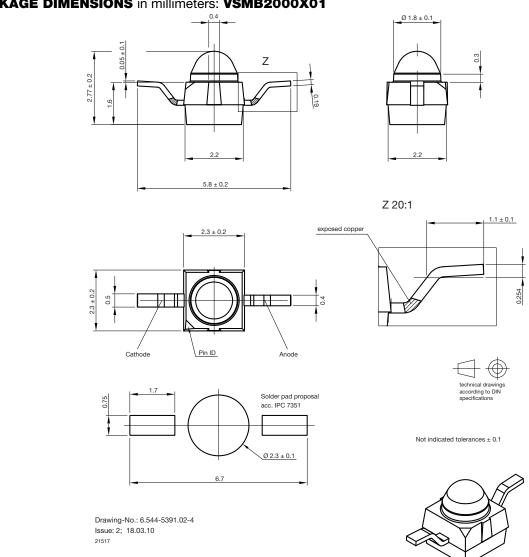
Conditions:  $T_{amb}$  < 30 °C, RH < 60 %

Moisture sensitivity level 2a, according to J-STD-020.

#### **DRYING**

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 °C (+ 5 °C), RH < 5 %.

#### PACKAGE DIMENSIONS in millimeters: VSMB2000X01

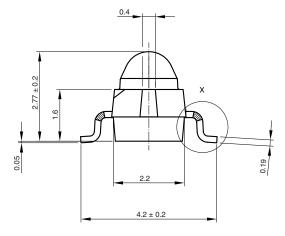


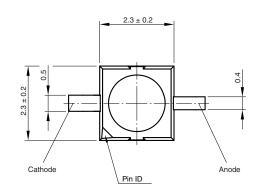
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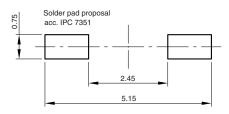
#### www.vishay.com

# Vishay Semiconductors

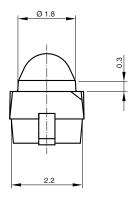
### PACKAGE DIMENSIONS in millimeters: VSMB2020X01

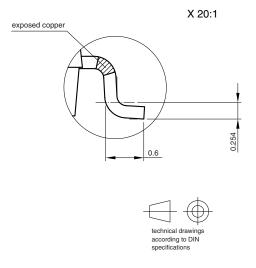




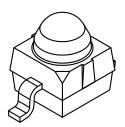


Drawing-No.: 6.544-5383.02-4 Issue: 4; 18.03.10

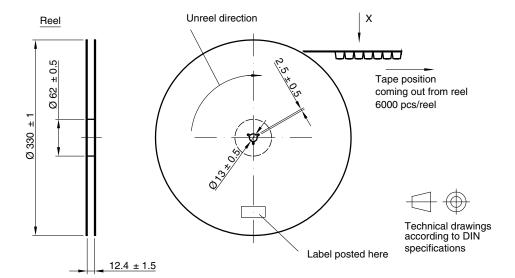




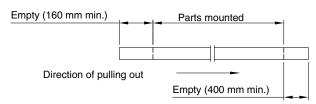




#### TAPING AND REEL DIMENSIONS in millimeters: VSMB2000X01

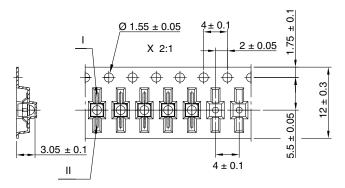


Leader and trailer tape:



#### Terminal position in tape

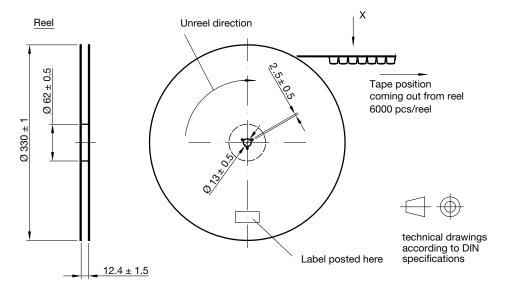
Device	Lead I	Lead II
VEMT2000		
VEMT2500	Collector	Emitter
VEMD2000		
VEMD2500	Cathada	Anode
VSMB2000	Cathode	Anode
VSMG2000		
VSMY2850RG	Anode	Cathode



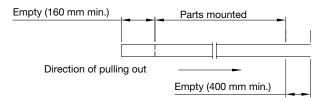
Drawing-No.: 9.800-5100.01-4 Issue: 2; 18.03.10

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#### TAPING AND REEL DIMENSIONS in millimeters: VSMB2020X01

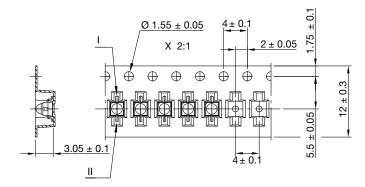


#### Leader and trailer tape:



#### Terminal position in tape

Device	Lead I	Lead II	
VEMT2020	Collector	Emitter	
VEMT2520	Collector	Emitter	
VSMB2020			
VSMG2020	Cathode	Anode	
VEMD2020	Calriode	Ariode	
VEMD2520			
VSMY2850G	Anode	Cathodo	
VSMB294008GC	Ariode	Cathode	



Drawing-No.: 9.800-5091.01-4

Issue: 3; 18.03.10

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